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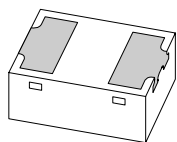
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Kind regards,

Team Nexperia



PMEG3002AELD

30 V, 0.2 A low V_F MEGA Schottky barrier rectifier

Rev. 1 — 19 April 2011

Product data sheet

1. Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD882D leadless ultra small Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

1.2 Features and benefits

- Forward current: $I_F \leq 0.2$ A
- Reverse voltage: $V_R \leq 30$ V
- Low forward voltage: $V_F \leq 480$ mV
- Ultra small and leadless SMD plastic package
- AEC-Q101 qualified
- Solderable side pads
- Package height typ. 0.37 mm

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications
- Ultra high-speed switching

1.4 Quick reference data

Table 1. Quick reference data

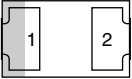
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{F(AV)}$	average forward current	square wave; $\delta = 0.5$; $f = 20$ kHz				
		$T_{amb} \leq 125$ °C	[1]	-	0.2	A
		$T_{sp} \leq 140$ °C	-	-	0.2	A
I_R	reverse current	$V_R = 10$ V	-	3.5	10	μ A
V_R	reverse voltage		-	-	30	V
V_F	forward voltage	$I_F = 200$ mA	[2]	430	480	mV

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[2] Pulse test: $t_p \leq 300$ μ s; $\delta \leq 0.02$.



2. Pinning information

Table 2. Pinning			
Pin	Description	Simplified outline	Graphic symbol
1	cathode	 Transparent top view	 <i>sym001</i>
2	anode		

[1] The marking bar indicates the cathode.

3. Ordering information

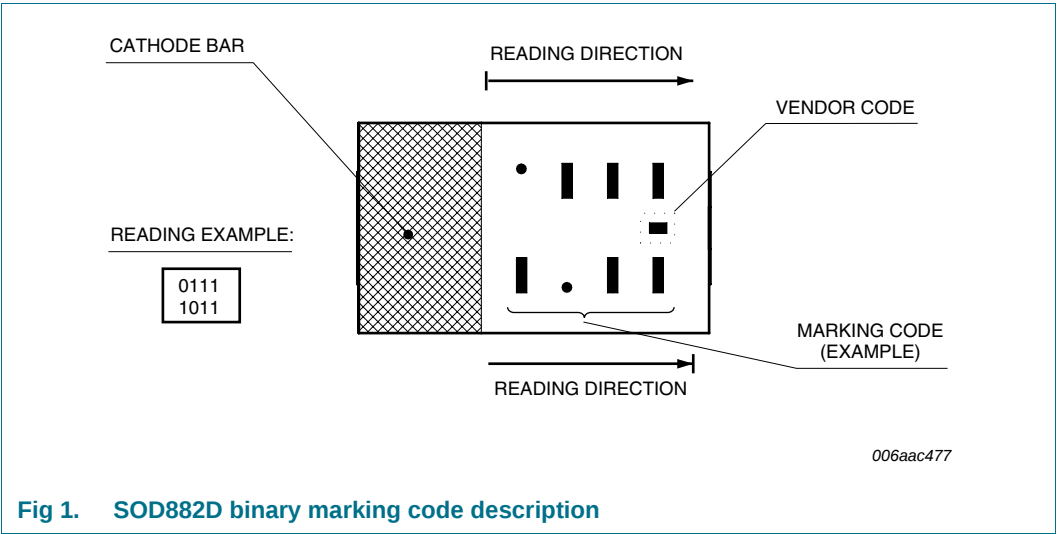
Table 3. Ordering information			
Type number	Package		
	Name	Description	Version
PMEG3002AELD	-	leadless ultra small plastic package; 2 terminals; body 1 × 0.6 × 0.4 mm	SOD882D

4. Marking

Table 4. Marking codes	
Type number	Marking code ^[1]
PMEG3002AELD	1101 0000

[1] For SOD882D binary marking code description, see [Figure 1](#).

4.1 Binary marking code description



5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage		-	30	V
$I_{F(AV)}$	average forward current	square wave; $\delta = 0.5$; $f = 20$ kHz			
		$T_{amb} \leq 125$ °C	[1] -	0.2	A
		$T_{sp} \leq 140$ °C	-	0.2	A
I_{FRM}	repetitive peak forward current	$t_p \leq 1$ ms; $\delta \leq 0.25$	-	1	A
I_{FSM}	non-repetitive peak forward current	square wave; $t_p = 8$ ms	[2] -	3	A
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[3] -	340	mW
			[1] -	660	mW
			[4] -	1000	mW
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		-55	+150	°C
T_{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[2] $T_j = 25$ °C prior to surge.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2] -	-	370	K/W
			[1][3] -	-	190	K/W
			[1][4] -	-	125	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[5] -	-	50	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [5] Soldering point of cathode tab.

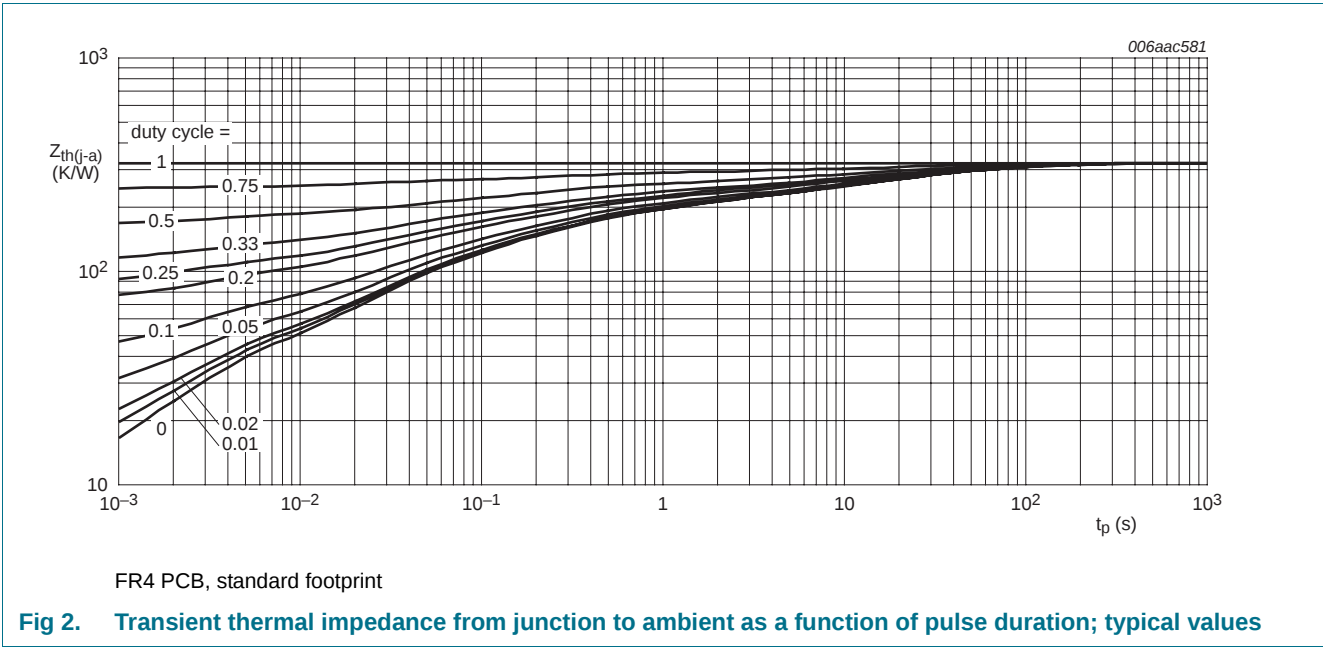
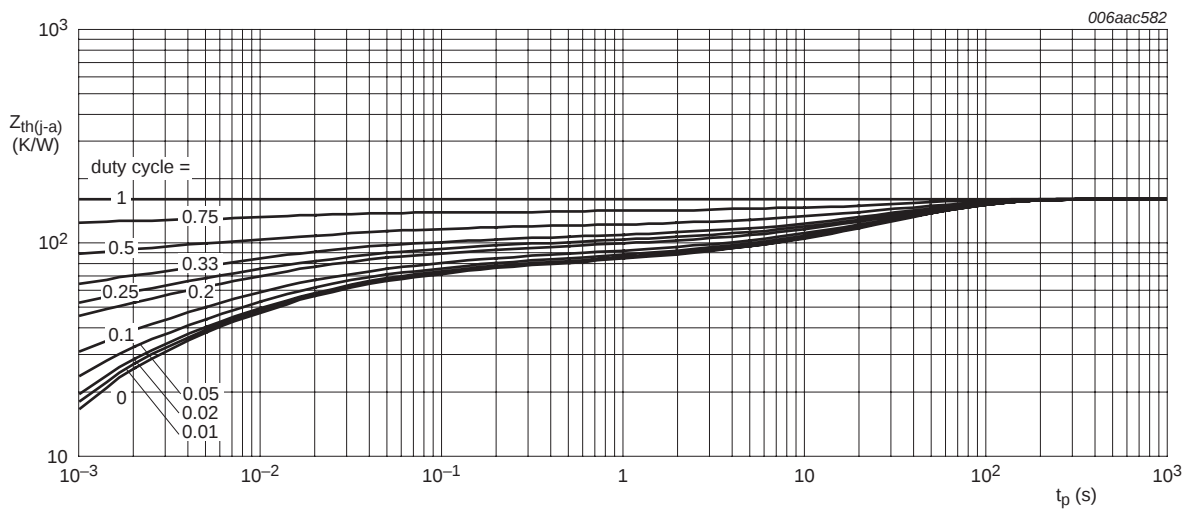
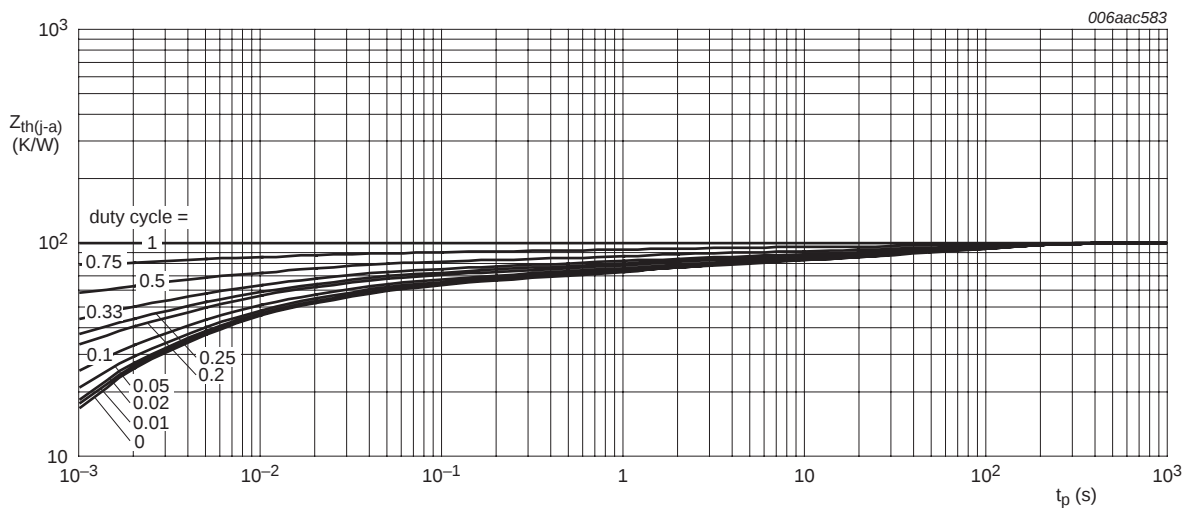


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for cathode 1 cm²

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB, Al₂O₃, standard footprint

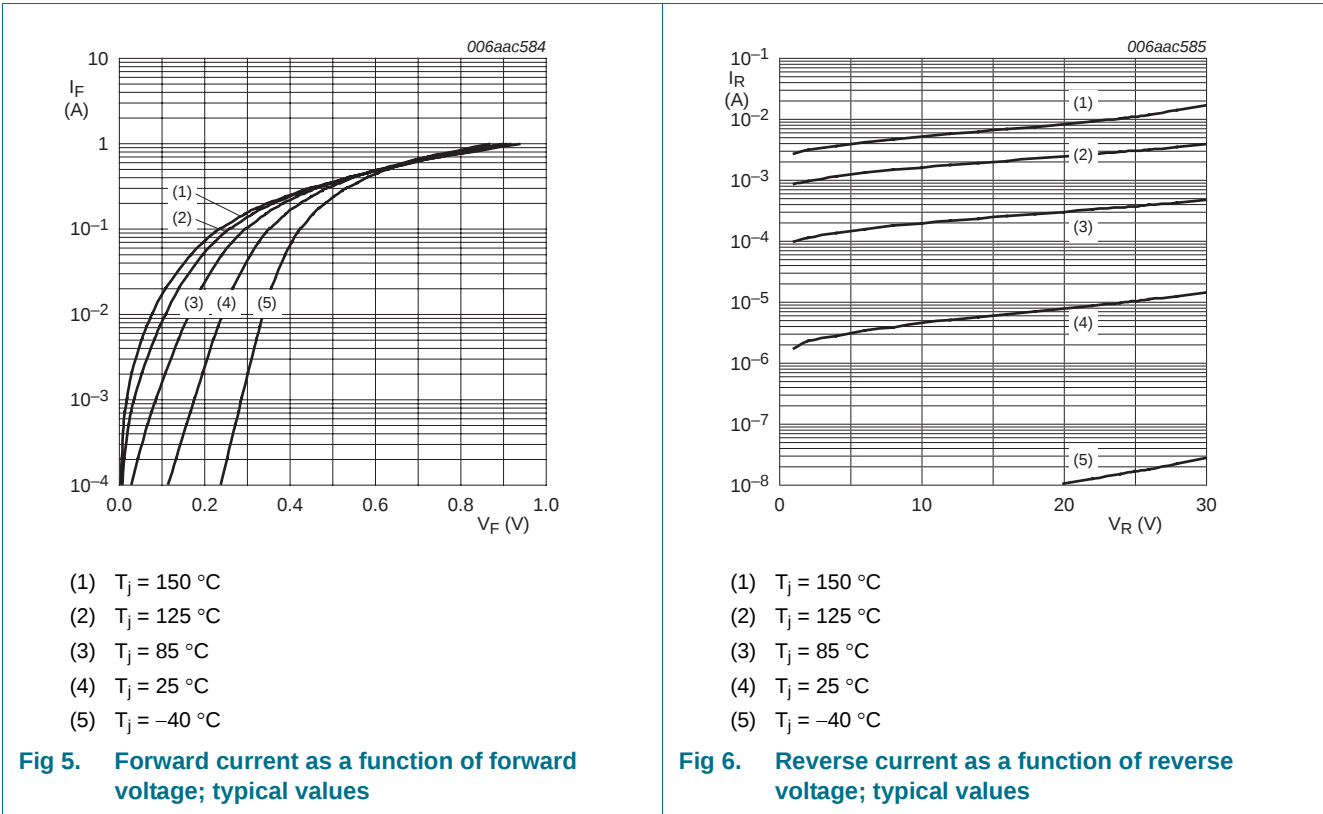
Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

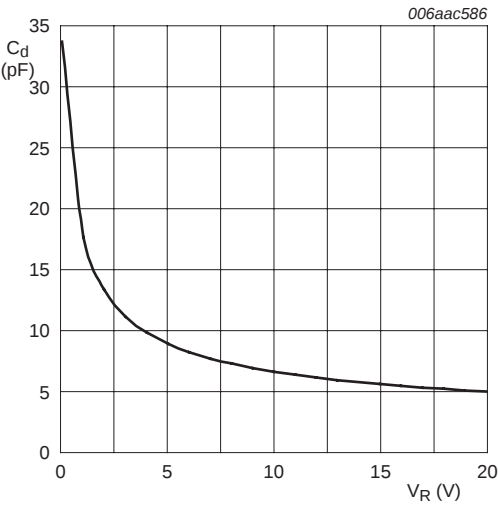
7. Characteristics

Table 7. Characteristics
 $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_F	forward voltage		[1]			
		$I_F = 0.1\text{ mA}$	-	120	190	mV
		$I_F = 1\text{ mA}$	-	180	250	mV
		$I_F = 10\text{ mA}$	-	250	300	mV
		$I_F = 100\text{ mA}$	-	355	400	mV
		$I_F = 200\text{ mA}$	-	430	480	mV
I_R	reverse current	$V_R = 10\text{ V}$	-	3.5	10	μA
		$V_R = 30\text{ V}$	-	12	50	μA
C_d	diode capacitance	$V_R = 1\text{ V}; f = 1\text{ MHz}$	-	18	25	pF
t_{rr}	reverse recovery time		[2]	6	-	ns

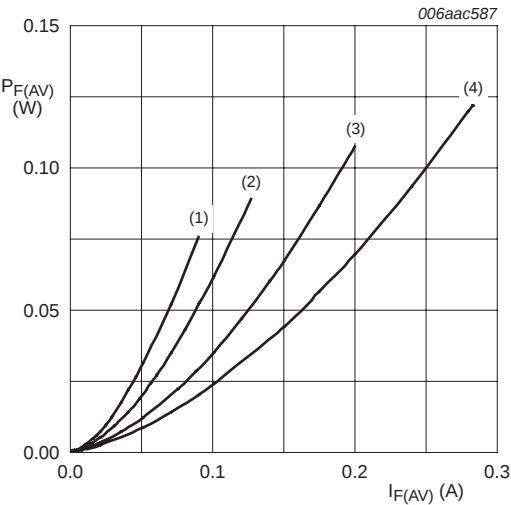
[1] Pulse test: $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$.
[2] When switched from $I_F = 10\text{ mA}$ to $I_R = 10\text{ mA}$; $R_L = 100\text{ }\Omega$; measured at $I_R = 1\text{ mA}$.





$f = 1\text{ MHz}$; $T_{\text{amb}} = 25\text{ }^{\circ}\text{C}$

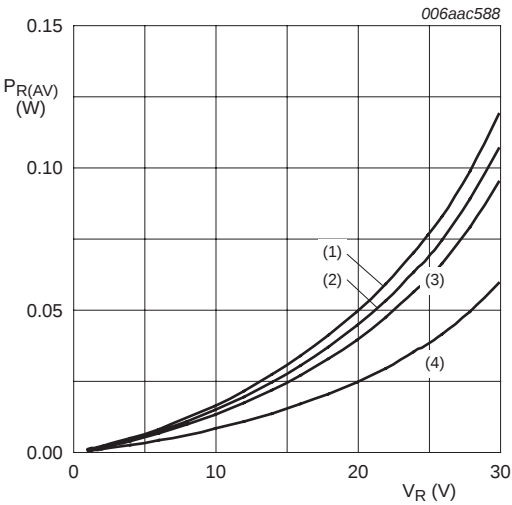
Fig 7. Diode capacitance as a function of reverse voltage; typical values



$T_j = 150\text{ }^{\circ}\text{C}$

- (1) $\delta = 0.1$
- (2) $\delta = 0.2$
- (3) $\delta = 0.5$
- (4) $\delta = 1$

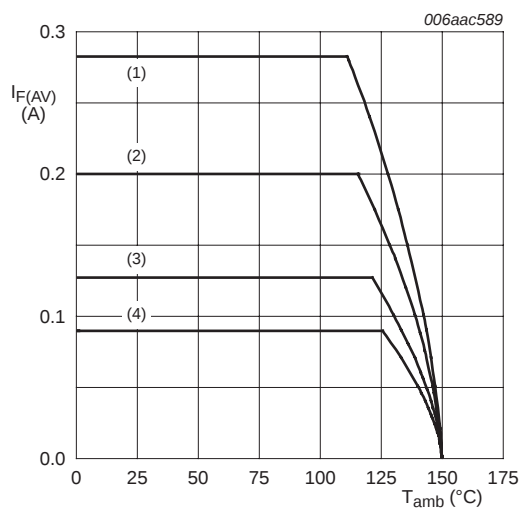
Fig 8. Average forward power dissipation as a function of average forward current; typical values



$T_j = 125\text{ }^{\circ}\text{C}$

- (1) $\delta = 1$
- (2) $\delta = 0.9$
- (3) $\delta = 0.8$
- (4) $\delta = 0.5$

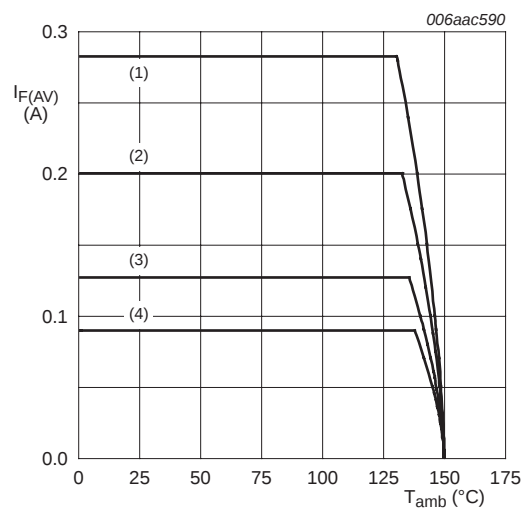
Fig 9. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint
 $T_j = 150$ °C

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; $f = 20$ kHz
- (3) $\delta = 0.2$; $f = 20$ kHz
- (4) $\delta = 0.1$; $f = 20$ kHz

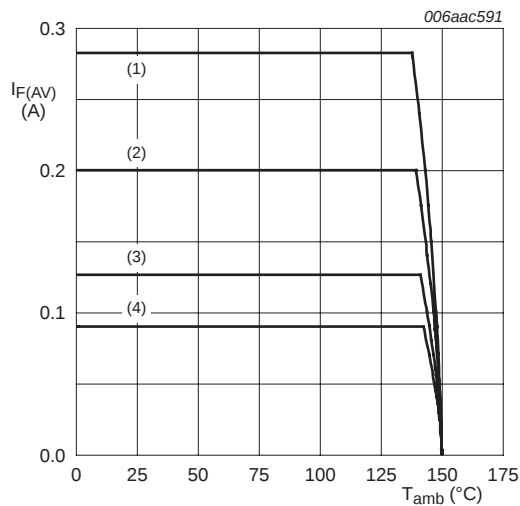
Fig 10. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm²
 $T_j = 150$ °C

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; $f = 20$ kHz
- (3) $\delta = 0.2$; $f = 20$ kHz
- (4) $\delta = 0.1$; $f = 20$ kHz

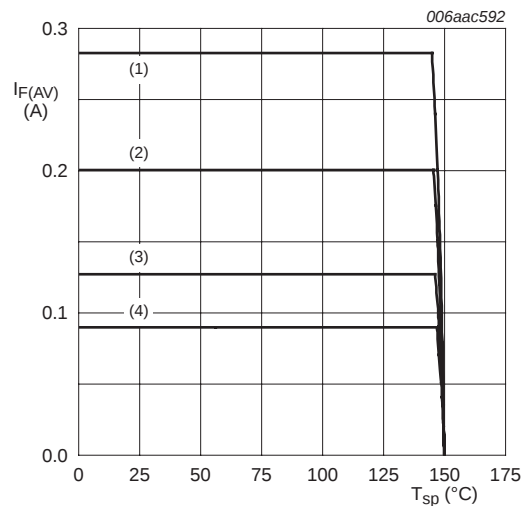
Fig 11. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al₂O₃, standard footprint
 $T_j = 150$ °C

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; $f = 20$ kHz
- (3) $\delta = 0.2$; $f = 20$ kHz
- (4) $\delta = 0.1$; $f = 20$ kHz

Fig 12. Average forward current as a function of ambient temperature; typical values



$T_j = 150$ °C

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; $f = 20$ kHz
- (3) $\delta = 0.2$; $f = 20$ kHz
- (4) $\delta = 0.1$; $f = 20$ kHz

Fig 13. Average forward current as a function of solder point temperature; typical values

8. Test information

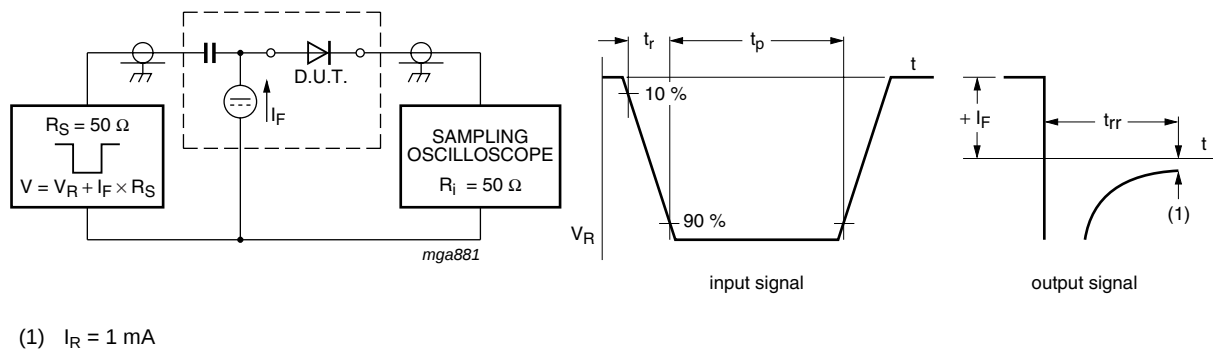


Fig 14. Reverse recovery time test circuit and waveforms

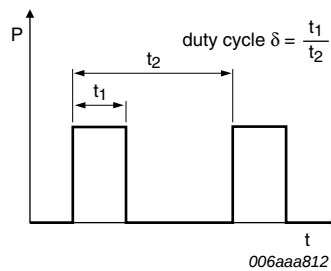


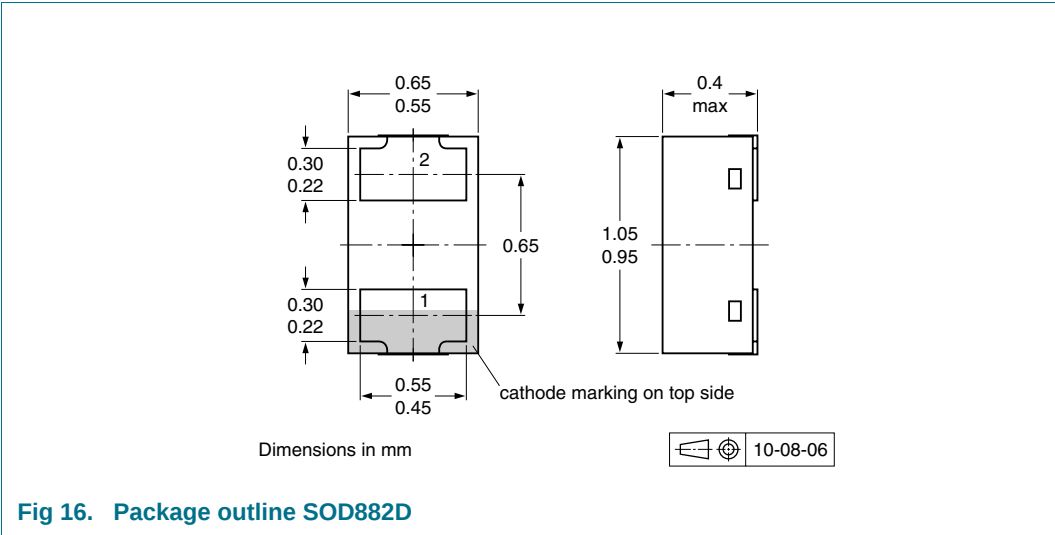
Fig 15. Duty cycle definition

The current ratings for the typical waveforms as shown in [Figure 10](#), [11](#), [12](#) and [13](#) are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



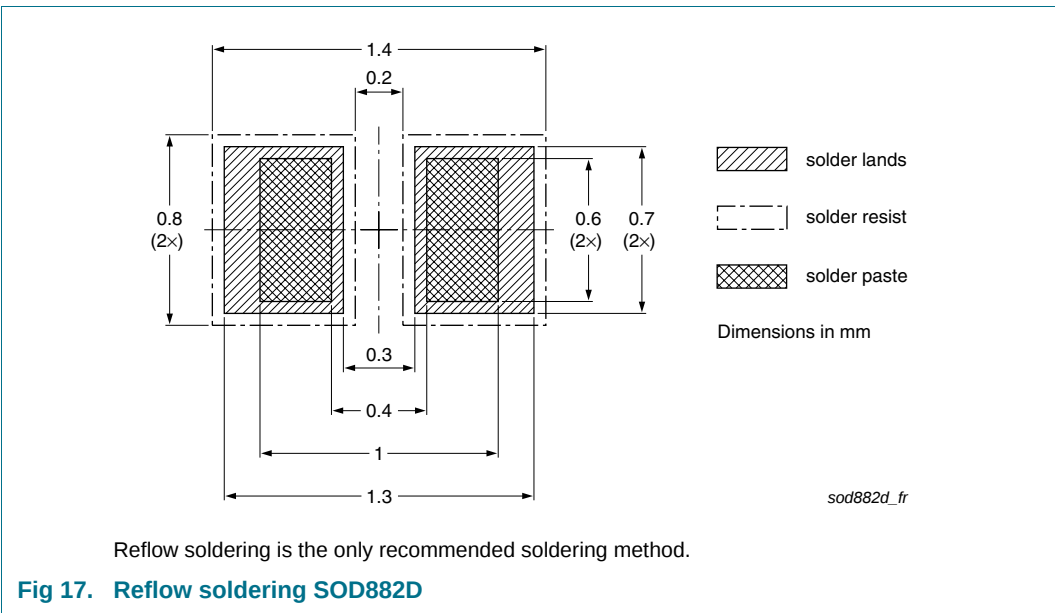
10. Packing information

Table 8. Packing methods
The indicated -xxx are the last three digits of the 12NC ordering code.[\[1\]](#)

Type number	Package	Description	Packing quantity
			10000
PMEG3002AELD	SOD882D	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering



12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG3002AELD v.1	20110419	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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